

CNR-SPIN (Genova, Italy)



HYBRID JOSEPHSON JUNCTIONS BASED ON InSb NANOFLAGS

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Outline

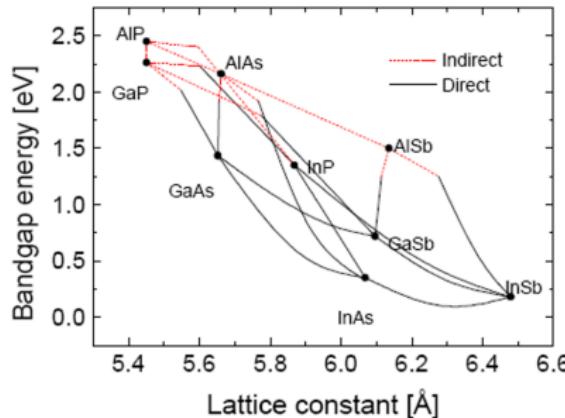
- ▶ InSb nanoflags for advanced devices
- ▶ InSb nanoflag Josephson junctions
- ▶ Superconducting diode in a single Josephson junction
- ▶ SQUID based on InSb nanoflags



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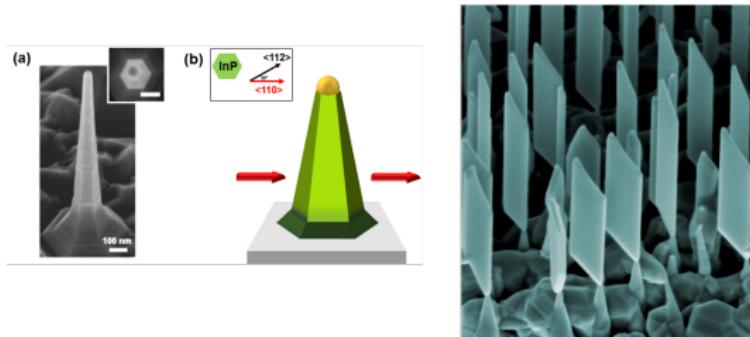
Why InSb?

- ▶ narrow bandgap $0.23\text{eV} \rightarrow$ mid-IR optoelectronics
- ▶ high bulk mobility $7.7 \cdot 10^4 \text{cm}^2/(\text{Vs}) \rightarrow$ high-speed electronic devices
- ▶ small effective mass $m = 0.018m_e \rightarrow$ low power electronic devices
- ▶ strong spin orbit interactions $E_{SOI} \sim 200\mu\text{eV}$ $g \sim 50 \rightarrow$ spintronics and topological devices



InSb nanoflags

InSb: challenging to grow 2D quantum wells
→ novel approach: 2D nanoflags

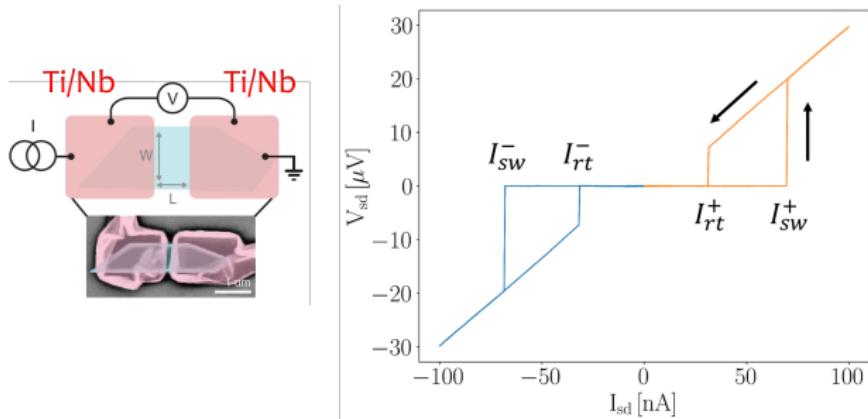


Tapered nanowires are used as stems

- ▶ length $\sim 2\mu\text{m}$
- ▶ width $\sim 700\text{nm}$
- ▶ thickness $\sim 100\text{nm}$
- ▶ defect-free structure
- ▶ mobility $\sim 29500\text{cm}^2/(\text{Vs})$
- ▶ mean free path $l_e \sim 500\text{nm}$

InSb Josephson junctions

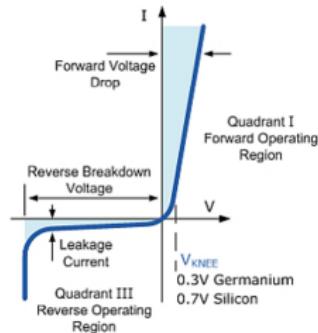
InSb nanoflag SNS devices



- Nb superconducting contacts $\Delta \sim 1.3\text{meV} \rightarrow \Delta^* \sim 250\mu\text{eV}$
- length $\sim 200\text{nm}$ and width $\sim 700\text{nm}$
- ballistic regime $I \ll I_e$
- high transparency $\tau \sim 0.9$

Diodes

The *pn* junction is at the basis of conventional electronics



Is it possible to obtain an analog for superconducting circuits?

Breaking of both time-reversal and inversion symmetry!

SDE experiments

Article

Observation of superconducting diode effect

Received: 14 March 2020; accepted: 10 June 2020; published: 23 June 2020
Takahiro Moriyama¹, Youichi Yamase¹ & Teruo Otsu²

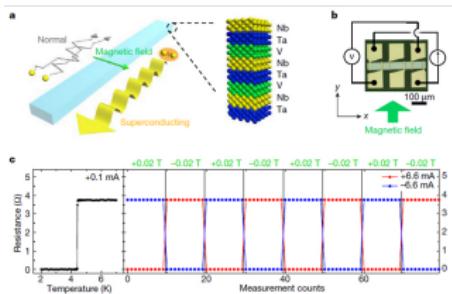
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Accepted: 23 June 2020

Published online: 19 April 2013

Takahiro Moriyama¹, Youichi Yanase² & Ieruo Ono³

Nonlinear optical and electrical effects associated with a lack of spatial inversion symmetry allow direction-selective propagation and transport of quantum particles, such as photons¹ and electrons²⁻⁹. The most common example of such nonreciprocal



F. Ando et al., *Nature* 584 (2020) 373.

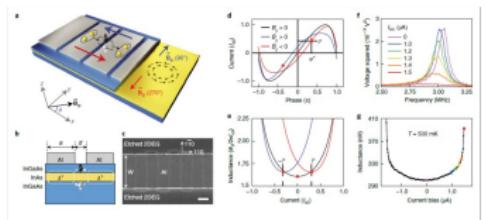
nature
nanotechnology

ARTICLES



Supercurrent rectification and magnetochiral effects in symmetric Josephson junctions

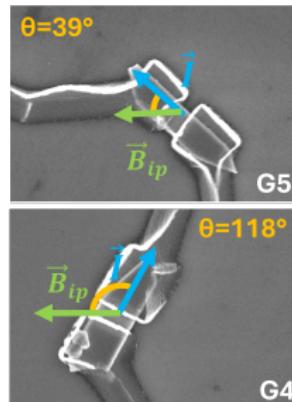
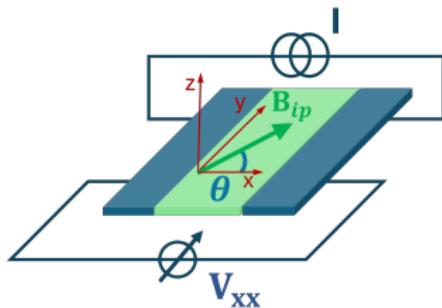
Christian Baumgartner¹⁸, Lorenz Fuchs¹⁸, Andreas Costa², Simon Reinhardt²¹, Sergei Gronin^{3,4}, Geoffrey C. Gardner^{2,4}, Tyler Lindemann^{4,5}, Michael J. Manfra^{3,4,5,6,7}, Paulo E. Faria Junior², Denis Kochan², Jaroslav Fabian², Nicola Paradiso^{2,12} and Christoph Strunk^{2,1}



C. Baumgartner et al., Nat. Nano 17 (2022) 39.

SDE in a single Josephson junction

InSb nanoflag planar Josephson junction



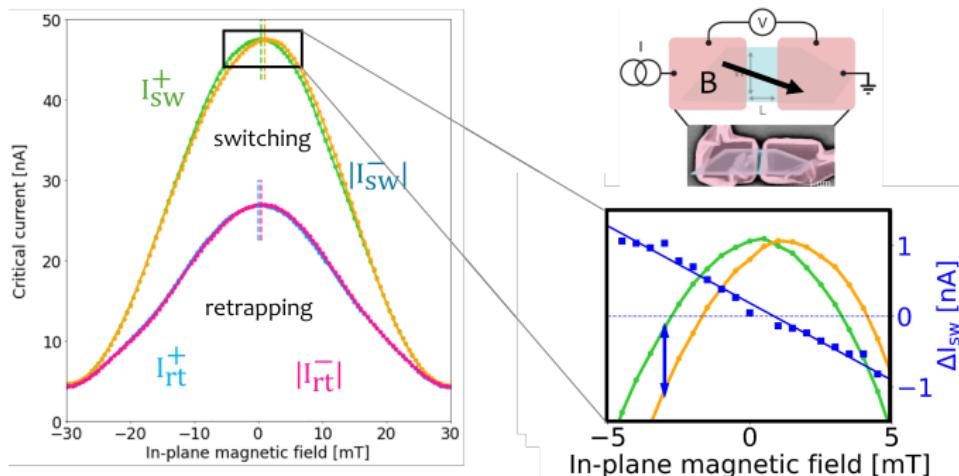
need for a planar B field

Turini et al NanoLetters 2022

Josephson diode effect

Supercurrent at 30mK

I_{SW}^{\pm} switching current in opposite bias directions

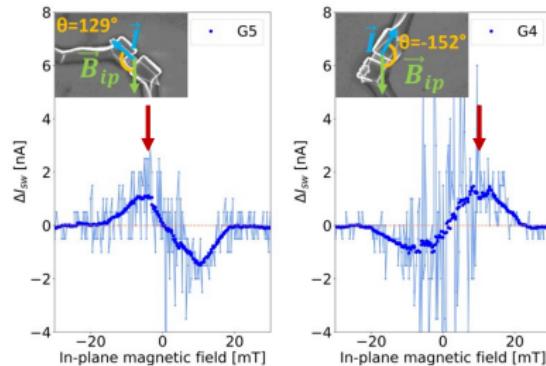


JDE is driven by magnetic field!

Supercurrent asymmetry

$$\Delta I_{SW} = I_{SW}^+ - |I_{SW}^-|$$

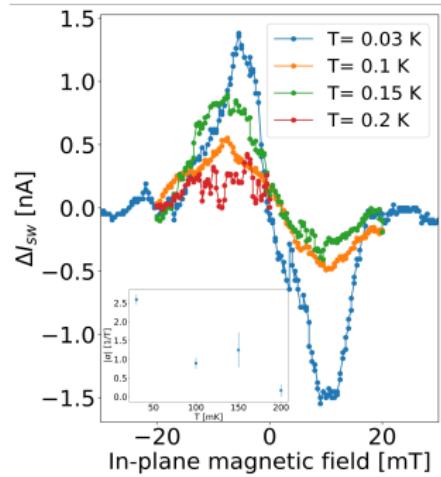
in-plane B_{ip} field dependence



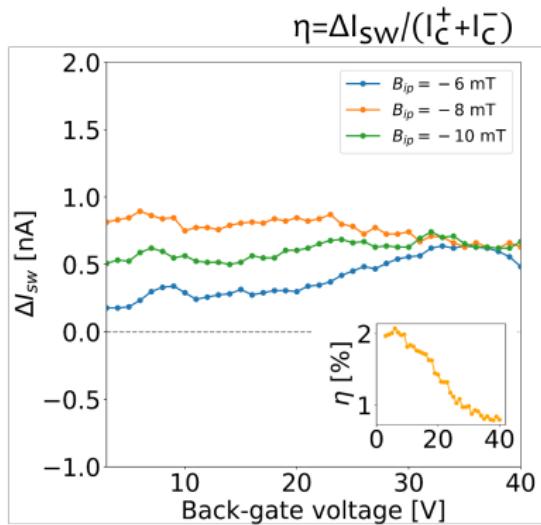
- ▶ anti-symmetric in B
- ▶ linear behaviour around $B = 0$
- ▶ rounded maxima
- ▶ suppression above $\sim 20\text{mT}$

Extrinsic parameters

JDE temperature dependence



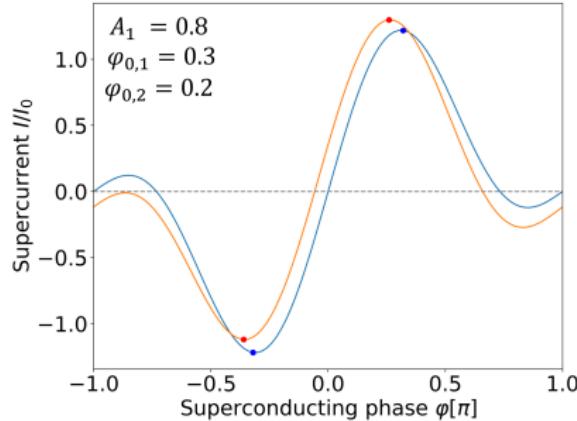
JDE gate-voltage dependence



JDE interpretation

- ballistic and short junction regime
- dominant Rashba SOI
- finite momentum pairing $q = g\mu_B B/v_F$
- high transparency $\tau \rightarrow$ skewed current-phase-relation (CPR)

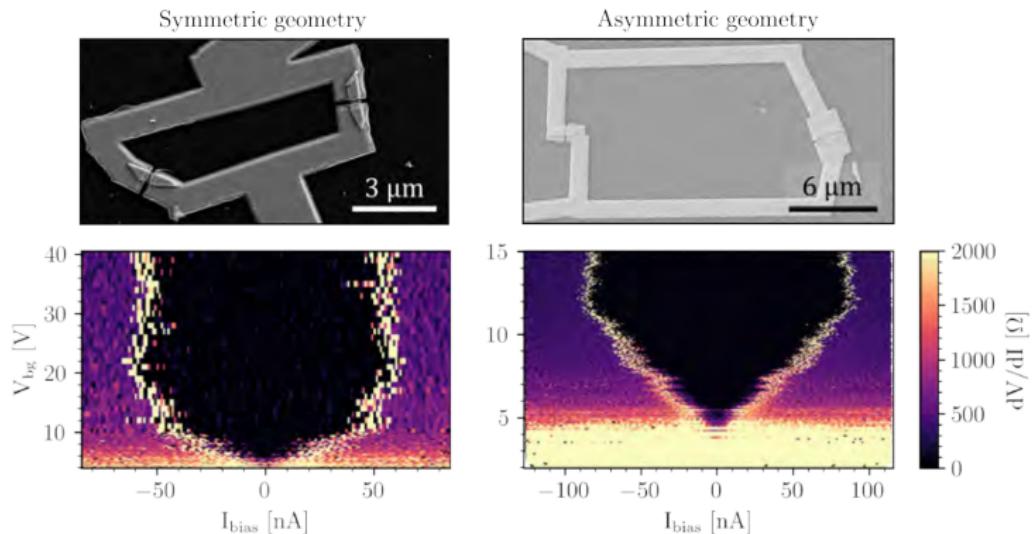
$$I = I_0 \sum_n c_n \sin(n\phi)$$



SQUID based on InSb nanoflags

How to inspect the CPR content?

SQUID with different geometries



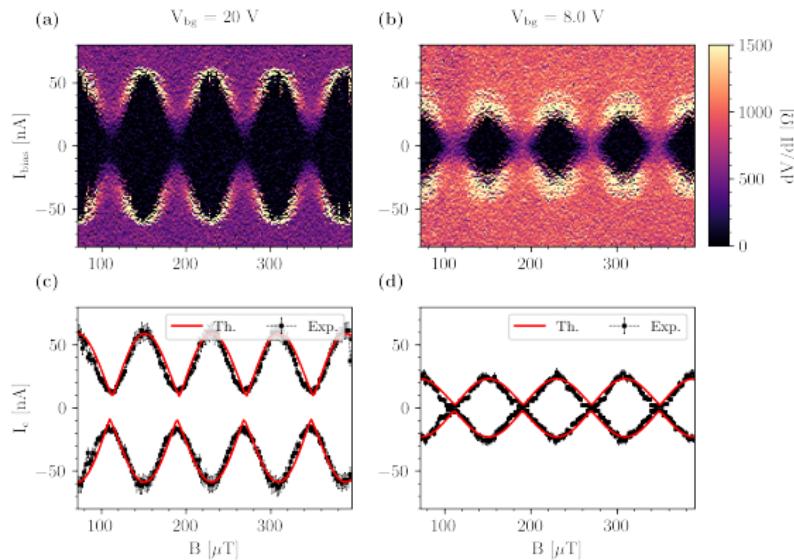
$$A_{\text{geo}}^{\text{sym}} = 13.6 \mu\text{m}^2 \quad A_{\text{geo}}^{\text{asym}} = 118 \mu\text{m}^2$$

Chieppa et al, NanoLetters 2025

SQUID response

$$I_{C, \text{ SQUID}} = \text{Max}_\varphi \left[I_1(\varphi) + I_2(\varphi - 2\pi \frac{\Phi}{\Phi_0}) \right]$$

Interference patterns in the symmetric geometry



High transparency τ at high V_{bg}

Numerical simulations

Effective two band model for InSb

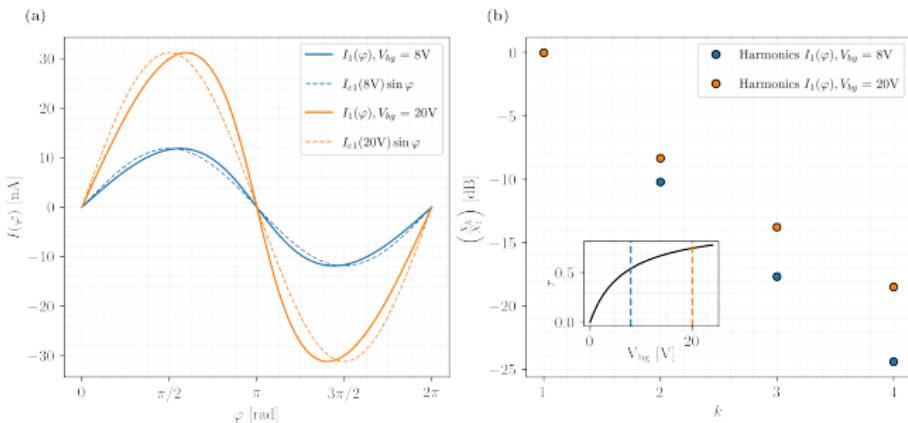
$$\mathcal{H}(\vec{k}) = \left(\frac{\hbar^2 \vec{k}^2}{2m^*} - \mu \right) \sigma_0 - \alpha_R k_y \sigma_x + \alpha_R k_x \sigma_y + \frac{g\mu_B}{2} B \sigma_z$$

- Bogoliubov-de Gennes formalism with Δ induced SC gap
- Tight-binding simulation
- SQUID geometry with two parallel Josephson junctions
- Recursive Green function method

Chieppa et al, NanoLetters (2025)

Skewed CPR

CPR of a single junction with different V_{bg}
Major skewness at high back-gate



JJ transparency modulated with V_{bg}

$$\tau = \frac{1}{1 + z^2(V_{bg})}$$

Conclusions

- ▶ InSb nanoflag based Josephson junction
- ▶ Josephson diode effect
- ▶ SQUID based on InSb nanoflags
- ▶ High harmonic contents and skewed CPRs

B. Turini et al, NanoLetters **22**, 8502 (2022)



A. Chieppa et al., NanoLetters: published online (2025)



Collaborations and projects

- ▶ **CNR-NANO:** S. Heun, L. Sorba, F. Giazotto, E. Strambini, V. Zannier, I. Verma, A. Crippa, S. Salimian, A. Iorio, B. Turini, A. Chieppa
- ▶ **Univ. Genova:** M. Sassetti, N. Traverso Ziani, S. Traverso, S. Fracassi

Project PRIN 2022 (MUR, Italy): "Topoflags"

